

## AMENDMENT TRANSMITTAL LETTER (Large Entity)

Applicant(s): Kao et al.

Docket No.

11675.107

Serial No.

08/720,693

Filing Date

October 2, 1996

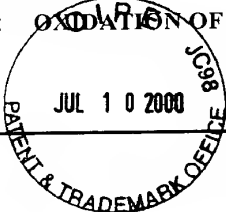
Examiner

George Fourson

Group Art Unit

2814

Invention: OXIDATION OF ION IMPLANTED SEMICONDUCTORS



TO THE ASSISTANT COMMISSIONER FOR PATENTS:

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

## CLAIMS AS AMENDED

	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXTRA CLAIMS PRESENT	RATE	ADDITIONAL FEE
TOTAL CLAIMS	44 -	44 =	0 x	\$18.00	\$0.00
INDEP. CLAIMS	6 -	6 =	0 x	\$78.00	\$0.00
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					\$0.00
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT					\$0.00

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TECHNOLOGY CENTER 2800

- ☒ No additional fee is required for amendment.
- ☐ Please charge Deposit Account No. \_\_\_\_\_ in the amount of \_\_\_\_\_
- A duplicate copy of this sheet is enclosed.
- ☐ A check in the amount of \_\_\_\_\_ to cover the filing fee is enclosed.
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- ☒ Any additional filing fees required under 37 C.F.R. 1.16.
- ☒ Any patent application processing fees under 37 CFR 1.17.

Signature

Dated: July 5<sup>th</sup>, 2000

Bradley K. DeSandro, Reg. No. 34,521



22901

PATENT TRADEMARK OFFICE

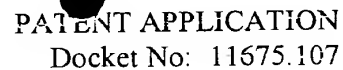
I certify that this document and fee is being deposited  
on July 5, 2000 with the U.S. Postal Service as  
first class mail under 37 C.F.R. 1.8 and is addressed to the  
Assistant Commissioner for Patents, Washington, D.C.  
20231.

Signature of Person Mailing Correspondence

Peggy R. Huft

Typed or Printed Name of Person Mailing Correspondence

CC:



In re application of

David Y. Kao, et al.

Serial No.: 08/720,693

Filed: October 2, 1996

For: OXIDATION OF ION IMPLANTED  
SEMICONDUCTORS

Examiner: George Fourson

12/B  
Range  
7/14/00

Group Art Unit  
2814

AMENDMENT B UNDER 35 U.S.C. § 1.115

Honorable Commissioner of Patents  
and Trademarks  
Washington, D.C. 20231

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Sir:

In response to the Office action mailed on April 12, 2000 (the "Office Action"), the Applicants submit this Amendment B and response.

IN THE SPECIFICATION

Page 14, line 19: change " 4 " to --7 --;

Page 17, line 11 and Page 23, line 2:

change "charge characteristic" to -- conductivity type --;

Page 25, line 15: change "17" to -- 15 --.

### IN THE Claims

In the claims, please amend Claims 1-33 as follows: